

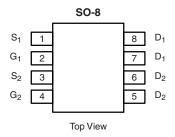
Dual N-Channel 20-V (D-S) MOSFET

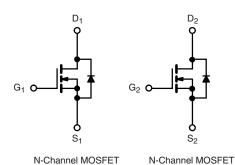
PRODUCT SUMMARY				
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A)		
20	0.025 at V _{GS} = 4.5 V	7.1		
20	0.035 at V _{GS} = 2.5 V	6.0		

FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET[®] Power MOSFET
- 100 % R_g Tested
- Compliant to RoHS Directive 2002/95/EC







ABSOLUTE MAXIMUM RATINGS Parameter	,	Symbol	Limit	Unit	
Drain-Source Voltage		V _{DS}	20	Oilit	
Gate-Source Voltage		V _{GS}	± 12	V	
0 11 0 1/7 150003	T _A = 25 °C	1	7.1		
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C	I _D	5.7		
Pulsed Drain Current (10 μs Pulse Width)		I _{DM}	40	A	
Continuous Source Current (Diode Conduction) ^a		I _S	1.7		
Mariana Barra Biratina di	T _A = 25 °C	P _D	2	W	
Maximum Power Dissipation ^a	T _A = 70 °C	' D	1.3	vv	
Operating Junction and Storage Temperature Ran	ige	T _J , T _{stg}	- 55 to 150	°C	

THERMAL RESISTANCE RATINGS						
Parameter	Symbol	Limit	Unit			
Maximum Junction-to-Ambient ^a	R _{thJA}	62.5	°C/W			

Notes

a. Surface Mounted on FR4 board, $t \le 10 \text{ s.}$



Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static				•			
Gate Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_D = 250 \mu A$			1.5	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 12 \text{ V}$			± 100	nA	
Zava Cata Valtaga Dvais Current	1	V _{DS} = 20 V, V _{GS} = 0 V	V 1		1		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 20 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55 ^{\circ}\text{C}$			μA		
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 5 \text{ V}, V_{GS} = 4.5 \text{ V}$	20			Α	
	В	$V_{GS} = 4.5 \text{ V}, I_D = 7.1 \text{ A}$		0.019	0.025	Ω	
Drain-Source On-State Resistance ^a	R _{DS(on)}	$V_{GS} = 2.5 \text{ V}, I_D = 6.0 \text{ A}$		0.026	0.035		
Forward Transconductance ^a	9 _{fs}	$V_{DS} = 10 \text{ V}, I_D = 7.1 \text{ A}$		27		S	
Diode Forward Voltage ^a	V_{SD}	I _S = 1.7 A, V _{GS} = 0 V			1.2	٧	
Dynamic ^b			•	•			
Total Gate Charge	Qg			9.5			
Gate-Source Charge	Q_{gs}	$V_{DS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V}, I_{D} = 7.1 \text{ A}$		1.5		nC	
Gate-Drain Charge	Q_{gd}			2.5		1	
Gate Resistance	R_g	f = 1 MHz		1.6	2.7	Ω	
Turn-On Delay Time	t _{d(on)}			10			
Rise Time	t _r	V_{DD} = 10 V, R_L = 10 Ω		15			
Turn-Off Delay Time	t _{d(off)}	$I_D\cong 1$ A, $V_{GEN}=4.5$ V, $R_g=10\Omega$		38		ns	
Fall Time	t _f			25			
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 1.7 A, dI/dt = 100 A/μs		26			

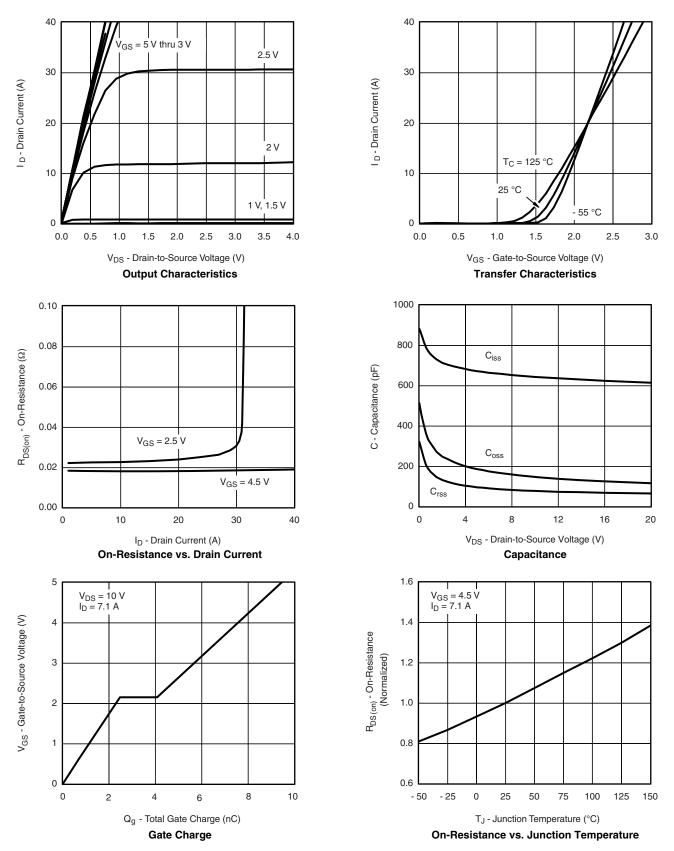
Notes:

- a. Pulse test; pulse width \leq 300 μ s, duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

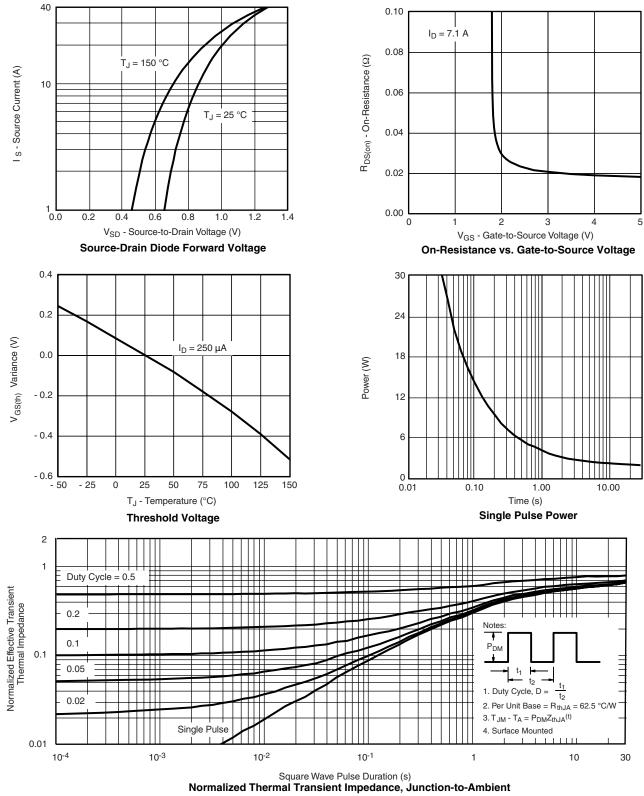


TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



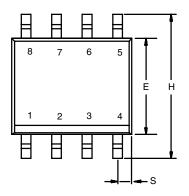


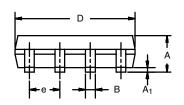
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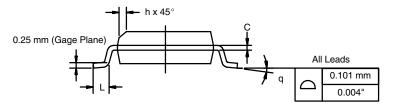




SOIC (NARROW): 8-LEAD JEDEC Part Number: MS-012







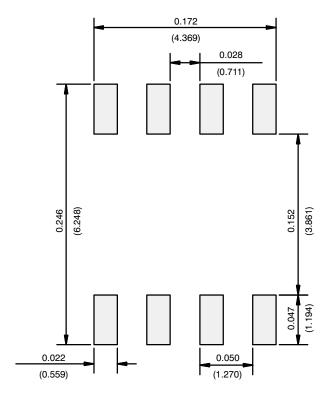
	MILLIM	IETERS	INC	HES	
DIM	Min	Max	Min	Max	
Α	1.35	1.75	0.053	0.069	
A ₁	0.10	0.20	0.004	0.008	
В	0.35	0.51	0.014	0.020	
С	0.19	0.25	0.0075	0.010	
D	4.80	5.00	0.189	0.196	
E	3.80	4.00	0.150	0.157	
е	1.27 BSC		0.050 BSC		
Н	5.80	6.20	0.228	0.244	
h	0.25	0.50	0.010	0.020	
L	0.50	0.93	0.020	0.037	
q	0°	8°	0°	8°	
S	0.44	0.64	0.018	0.026	
ECN: C-06527-Rev. I, 11-Sep-06					

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DWG: 5498



RECOMMENDED MINIMUM PADS FOR SO-8



Recommended Minimum Pads Dimensions in Inches/(mm)



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